

# SAMYANG ELECTRONICS MBR4030CT --- MBR40200CT

## SCHOTTKY BARRIER RECTIFIER

## VOLTAGE RANGE: 30 --- 200 V CURRENT:40.0A

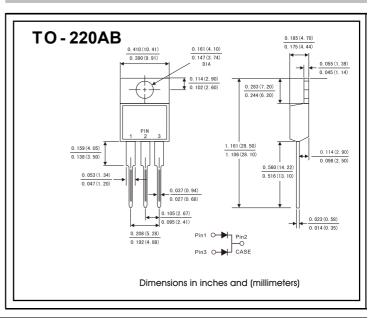
## **FEATURES**

- Metal-semiconductor junction with guard ring

- For use in low voltage, high frequency inverters free wheeling, and polarity protection applications

### **MECHANICAL DATA**

- ◇ Polarity: As marked
- ♦ Weight: 0.08ounces,2.24 grams



### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

	Symbols	<b>MBR</b> 4030CT	<b>MBR</b> 4035CT	<b>MBR</b> 4040CT	MBR 4045CT	<b>MBR</b> 4050CT	MBR 4060CT	MBR 40100CT	MBR 40150CT	<b>MBR</b> 40200CT	Units
Maximum repetitive peak reverse voltage	Vrrm	30	35	40	45	50	60	100	150	200	Volts
Maximum RMS voltage	VRMS	21	25	28	32	35	42	70	105	140	Volts
Maximum DC blocking voltage	VDC	30	35	40	45	50	60	100	150	200	Volts
Maximum average forward Per leg rectified current(see Fig.1) Total device	I(AV)	20.0 40.0									Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	<b>İ</b> FSM	300.0							Amps		
Maximum instantaneous forward voltage at 40.0 A	VF	0.60			0.3	75	0.85	0.	95	Volts	
Maximum instantaneous reverse current at rated DC blocking voltage(Note 1) $I_c = 25^{\circ}C$ $I_c = 125^{\circ}C$	lR	0.2 30 50							mA		
Typical thermal resistance (Note 2)	R₀JC	3.0									°C/W
Operating junction temperature range	TJ	-65 to+150									°C
Storage temperature range	Tstg	-65 to+150									°C

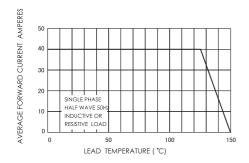
NOTE: 1. Pulse test:300us pulse width,1% duty cycle.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

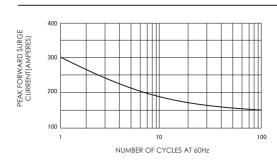
3. Thermal resistance junction to ambient

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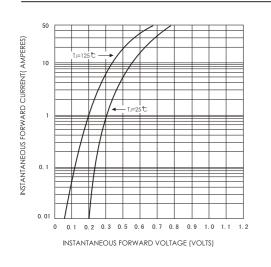
## FIG.1-FORWARD CURRENT DERATING CURVE



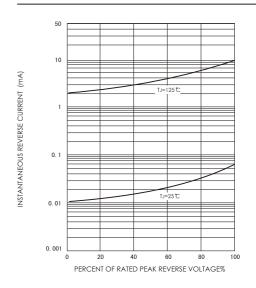
## FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT



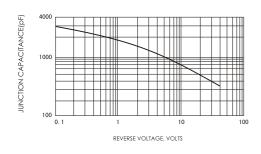
## FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



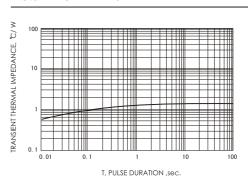
### FIG.4-TYPICAL REVERSE CHARACTERISTICS



### FIG.5-TYPICAL JUNCTION CAPACITANCE



### FIG.6-TYPICAL TRANSIENT THERMAL IMPEDANCE



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